

RBA80N04DANS-4UB03

N-Channel Power MOSFET

 $40V - 80A - 3.0m\Omega$

Description

Renesas SO8-FL technology in 5x6mm² flat-lead package designed for supporting high current with copper clip-applied, compact & efficient designs and including optimal thermal performance. AEC-Q101 qualified MOSFET and PPAP capable suitable for automotive applications.

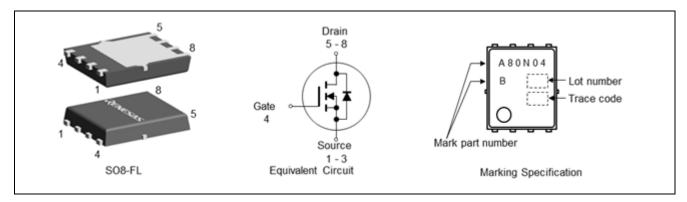
Features

- Standard level gate drive voltage: V_{GS(th)} = 2.0~4.0V
- Low on-state resistance to minimize conduction losses: $R_{DS(on)} = 3.0 \text{m}\Omega$ Max.
- Low input capacitance to minimize driver losses
- Small footprint (5x6mm²) with compact design
- AEC-Q101 qualified
- PPAP capable
- Pb-free lead plating: RoHS compliant
- MSL1 classified according to IPC/JEDEC J-STD-020

Application

• Automotive: 12V/24V load EPS, ABS, BMS, e-fuse, etc.

Outline



Absolute Maximum Ratings

(T_i=25°C unless otherwise notice.)

| Item | Symbol | Ratings | Unit |
|--------------------------|----------------------------------|------------|------|
| Drain to Source Voltage | V _{DSS} | 40 | V |
| Gate to Source Voltage | V _{GSS} | ±20 | V |
| Drain Current (DC) | I _{D(DC)} Notes1,2,5 | ±80 | Α |
| Drain Current (pulse) | I _{D(pulse)} Notes1,3,5 | ±240 | Α |
| Power Dissipation | P _D Notes1,5 | 79 | W |
| Junction Temperature | Tj | 175 | °C |
| Storage Temperature | T _{stg} | -55 to 175 | °C |
| Single Avalanche Current | I _{AS} Notes4 | 31 | A |
| Single Avalanche Energy | E _{AS} Notes4 | 96 | mJ |

Thermal Resistance

| Item | Symbol | Max. | Unit |
|-------------------------------------|-----------------------------|------|------|
| Junction to Case Thermal Resistance | R _{th(j-c)} Notes5 | 1.9 | °C/W |

Electrical Characteristics

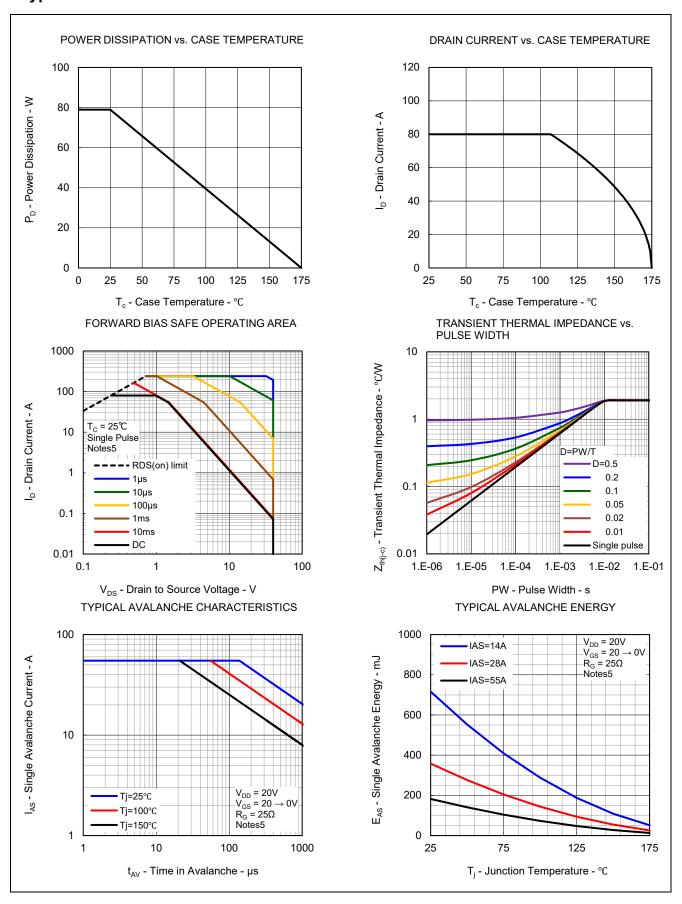
(T_j=25°C unless otherwise notice.)

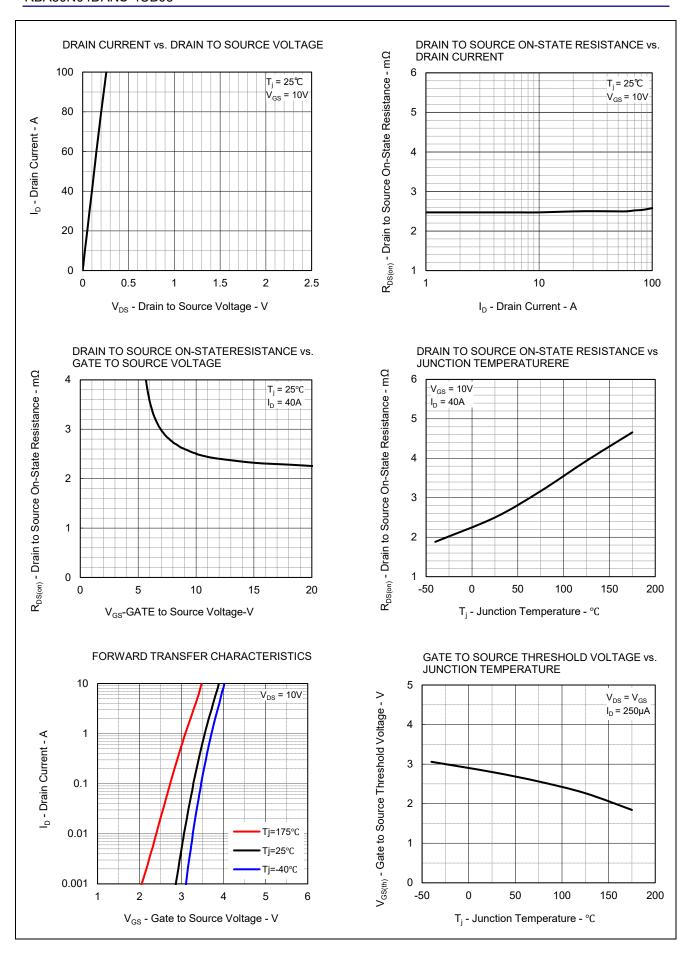
| Item | Symbol | Min | Тур | Max | Unit | Test Conditions |
|-------------------------------------|---------------------|-----|------|------|------|---|
| Zero Gate Voltage Drain Current | I _{DSS} | _ | _ | 1 | μA | $V_{DS} = 40 \text{ V}, V_{GS} = 0 \text{ V}$ |
| Gate Leakage Current | I _{GSS} | _ | _ | ±100 | nA | V_{GS} = \pm 20 V, V_{DS} = 0 V |
| Gate to Source Threshold Voltage | $V_{GS(th)}$ | 2.0 | _ | 4.0 | V | $V_{DS} = V_{GS}, I_{D} = 250 \ \mu A$ |
| Drain to Source On-state Resistance | R _{DS(on)} | _ | 2.5 | 3.0 | mΩ | $V_{GS} = 10 \text{ V}, I_D = 40 \text{ A}$ |
| Input Capacitance | C _{iss} | _ | 2690 | _ | pF | V _{DS} = 25 V |
| Output Capacitance | Coss | _ | 290 | _ | pF | $V_{GS} = 0 V$ |
| Reverse Transfer Capacitance | C _{rss} | _ | 215 | _ | pF | f = 1 MHz |
| Gate resistance | R _g | _ | 2.1 | _ | Ω | |
| Turn-on Delay Time | t _{d(on)} | _ | 21 | _ | ns | $V_{DD} = 20 \text{ V}, I_D = 40 \text{ A}$ |
| Rise Time | t _r | _ | 19 | _ | ns | V _{GS} = 10 V |
| Turn-off Delay Time | t _{d(off)} | _ | 59 | _ | ns | $R_G = 5 \Omega$ |
| Fall Time | t _f | _ | 17 | _ | ns | |
| Total Gate Charge | Q_g | _ | 56 | _ | nC | V _{DD} = 20 V |
| Gate to Source Charge | Q_{gs} | _ | 13 | _ | nC | $V_{GS} = 10 \text{ V}$ |
| Gate to Drain Charge | Q_{gd} | _ | 15 | | nC | $I_D = 40 A$ |
| Body Diode Forward Voltage | $V_{F(S-D)}$ | _ | 0.83 | 1.5 | V | I _F = 40 A, V _{GS} = 0 V |
| Reverse Recovery Time | t _{rr} | _ | 38 | | ns | I _F = 40 A, V _{GS} = 0 V |
| Reverse Recovery Charge | Q _{rr} | _ | 41 | _ | nC | di/dt = 100 A/μs |

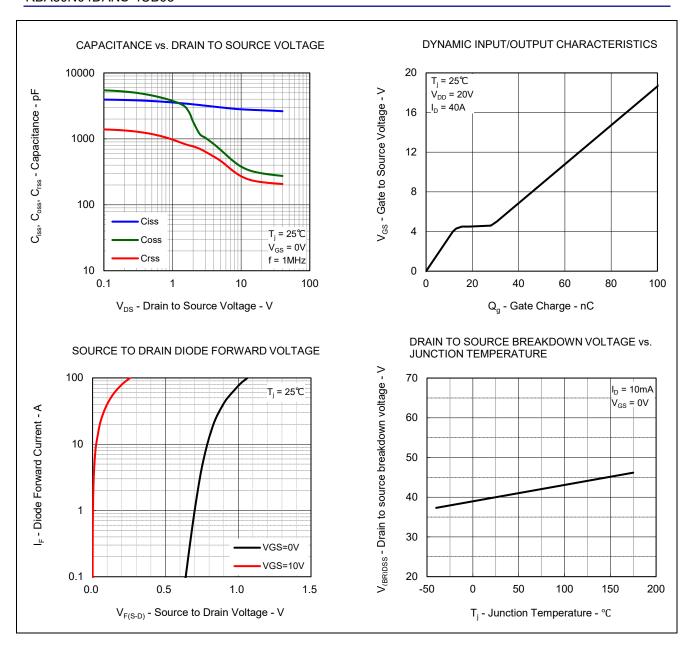
Notes 1. $T_c = 25$ °C

- 2. Value is limited by overall system design including PCB.
- 3. PW \leq 10 μs , Duty Cycle \leq 1%
- 4. L = 100 μH , V_{DD} = 20V , V_{GS} = 20 \rightarrow 0V , R_{G} = 25 Ω
- 5. Defined by design. Not subject to production test.

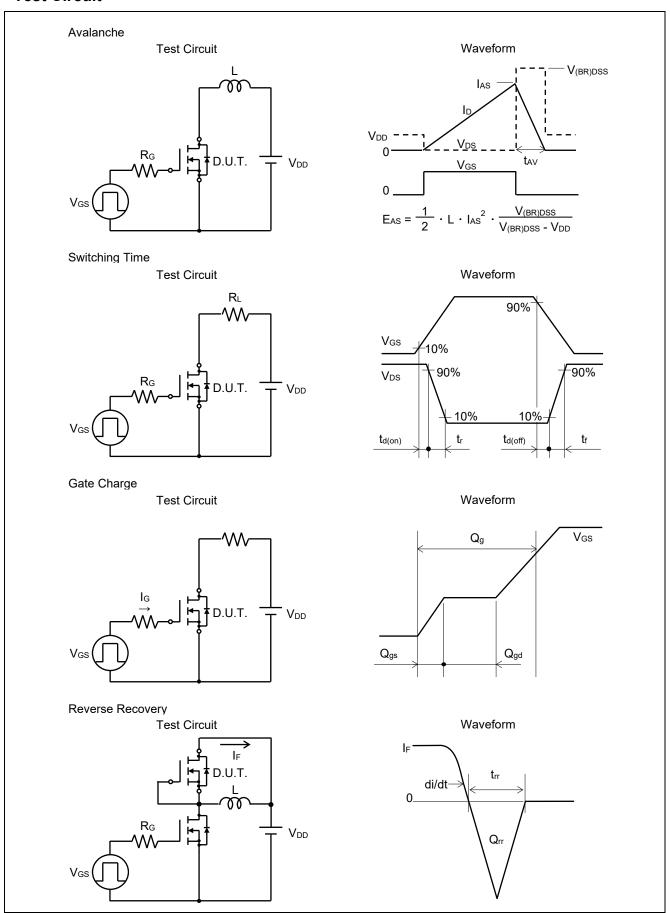
Typical Characteristics



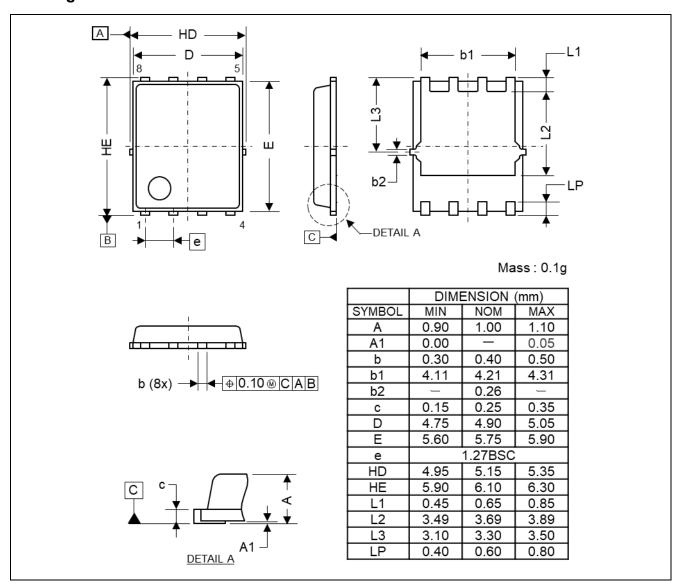




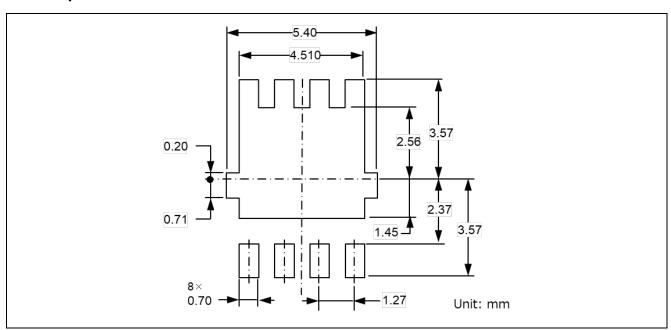
Test Circuit



Package Dimensions



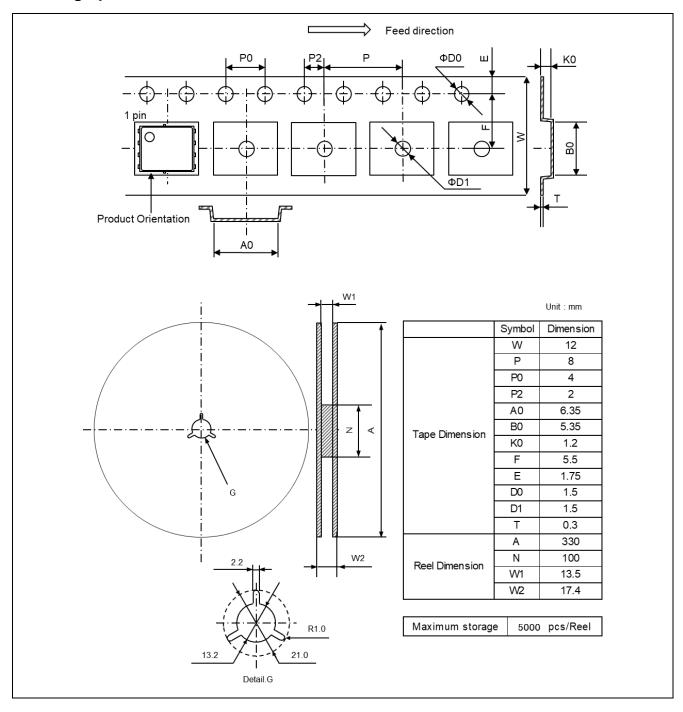
Mount pad



Ordering Information

| Part No. | Packing | Quantity |
|------------------------|---------|--------------|
| RBA80N04DANS-4UB03#HB0 | Taping | 5000pcs/reel |

Packing Specification



Remark: Strong electric field, when exposed to this device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it once, when it has occurred.

Continuous heavy condition (e.g. high temperature/voltage/current or high variation of temperature) may affect reliability even if it is within the absolute maximum ratings. Please consider derating condition for appropriate reliability in reference Renesas Semiconductor Reliability Handbook.

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